

P.O. Box 747
Falls Church, Virginia 22040-0747
Phone: (703) 205-8000
Fax: (703) 205-8050
(703) 698-8590 (GIV)

Birch, Stewart, Kolasch & Birch, LLP

Fax

To: Examiner David Vu
USPTO
Group 2818

From: Michael K. Mutter

FAX COPY RECEIVED

FEB 25 2002

TECHNOLOGY CENTER 2800

Fax: 703-872-9319

Date: February 25, 2002

Phone:

Pages: 17 (including cover sheet)

Your Ref.: SN 09/720,329

Our Ref.: 3672-110P

Re: Response to After
Final Office Action

CC:

☒ Urgent ☐ For Review ☐ Please Comment ☐ Please Reply ☐ Please Recycle

This transmission is intended for the sole use of the individual and entity to whom it is addressed, and may contain information that is privileged, confidential, and exempt from disclosure under applicable law. You are hereby notified that any dissemination, distribution, or duplication of this transmission by someone other than the intended addressee or its designated agent is strictly prohibited. If your receipt of this transmission is in error, please notify this firm immediately by collect call to (703) 205-8000, and send the original transmission to us by return mail at the address above.

Comments:

Please hand-deliver the attached
Response to David Vu.

Thank you.

BOX AF
REPLY UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP 2818

PATENT
3672-0110P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: Lucimara S. ROMAN et al. Conf.: 9297
 Appl. No.: 09/720,329 Group: 2818
 Filed: February 6, 2001 Examiner: VU, DAVID
 For: A METHOD IN FABRICATION OF ORGANIC THIN-FILM
 SEMICONDUCTING SERVICES

LARGE ENTITY TRANSMITTAL FORM
FOR REPLY AFTER FINAL UNDER 37 C.F.R. § 1.116

FAX COPY RECEIVED

FEB 25 2002

TECHNOLOGY CENTER 2800

BOX AF
 Assistant Commissioner for Patents
 Washington, DC 20231

February 25, 2002

Sir:

Transmitted herewith is an amendment in the above-identified application.

- ☐ The enclosed document is being transmitted via the Certificate of Mailing provisions of 37 C.F.R. § 1.8.
- ☒ The enclosed document is being transmitted via facsimile.

The fee has been calculated as shown below:

	CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NUMBER PREVIOUSLY PAID FOR		PRESENT EXTRA	RATE	ADDITIONAL FEE
TOTAL	18	-	20	=	0	\$ 18	\$0.00
INDEPENDEN	2	-	3	=	0	\$ 84	\$0.00
<input type="checkbox"/> FIRST PRESENTATION OF A MULTIPLE DEPENDENT CLAIM						\$280	\$0.00
						TOTAL	\$0.00

Appl. No. 09/720,329

- ☐ Petition for () month(s) extension of time pursuant to 37 C.F.R. §§ 1.17 and 1.136(a). \$0.00 for the extension of time.
- ☒ No fee is required.
- ☐ Check(s) in the amount of \$0.00 is(are) enclosed.
- ☐ Please charge Deposit Account No. 02-2448 in the amount of \$0.00. This form is submitted in triplicate.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. §§1.16 or 1.17; particularly, extension of time fees.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

By


Michael K. Mutter, #29,680MKM/gf
3672-0110PP.O. Box 747
Falls Church, VA 22040-0747
(703) 205-8000

(Rev. 08/27/01)


FAX COPY RECEIVED

Certificate of Transmission
I hereby Certify that this correspondence is being
transmitted to the Patent and
Trademark Office:

On

2-25-02

TECHNOLOGY CENTER 2800


Gail L. Frohnert
Typed or printed name of person signing certificate

#12
Amot
3-2-02
aej

**BOX AF
RESPONSE UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP 2818**

PATENT
3672-0110P

IN THE U. S. PATENT AND TRADEMARK OFFICE

APPLICANTS: Lucimara S. ROMAN et al. CONF.: 9297
APPLN. NO.: 09/720,329 GROUP: 2818
FILED: February 6, 2001 EXAMINER: VU, David
FOR: A METHOD IN FABRICATION OF ORGANIC THIN-FILM
SEMICONDUCTING SERVICES

FAX COPY RECEIVED
FEB 25 2002

AMENDMENT UNDER 37 C.F.R. § 1.116

TECHNOLOGY CENTER 2800

February 25, 2002

BOX AF
Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Responsive to the Examiner's Office Action dated November 23, 2001, the following amendments and Remarks are respectfully submitted in connection with the above-identified application.

IN THE CLAIMS:

Sub A17
C1
1. (Amended) A method in the fabrication of an electrode structure for an organic thin-film semiconducting device, wherein the semiconducting device is a rectifying diode with a high rectification ratio of an organic thin-film transistor or a hybrid organic/inorganic thin-film transistor comprises